Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.



Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights
 of third parties by or arising from the use of Renesas Electronics products or technical information described in this document.
 No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights
 of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.



NPN SILICON GERMANIUM RF TRANSISTOR

NESG240033

NPN SiGE RF TRANSISTOR FOR UHF-BAND, LOW NOISE, LOW DISTORTION AMPLIFICATION 3-PIN MINIMOLD (33 PKG)

FEATURES

- The device is an ideal choice for low noise, low distortion amplification.
 - NF = 0.75 dB TYP. @ $V_{CE} = 5 \text{ V}$, $I_{C} = 15 \text{ mA}$, f = 1 GHz
- Po (1 dB) = 23.5 dBm TYP. @ $V_{CE} = 5 \text{ V}$, Ic (set) = 40 mA, f = 1 GHz
- OIP3 = 35.5 dBm TYP. @ $V_{CE} = 5 V$, $I_{C (set)} = 40 mA$, f = 1 GHz
- Maximum stable power gain: MSG =13.0 dB TYP. @ VcE = 5 V, Ic = 40 mA, f = 1 GHz
- SiGe HBT technology (UHS2) : fT = 10.5 GHz
- This product is improvement of ESD of NESG2xxx series.
- 3-pin minimold (33 PKG)

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG240033	NESG240033-A	3-pin minimold (33 PKG) (Pb-Free)	50 pcs (Non reel)	8 mm wide embossed taping Pin 3 (Collector) face the perforation side
NESG240033-T1B	NESG240033-T1B-A		3 kpcs/reel	of the tape

Remark To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vcво	5.5	V
Collector to Emitter Voltage	Vces	13	V
Collector to Emitter Voltage	Vceo	5.5	V
Base Current Note 1	Ів	36	mA
Collector Current	lc	400	mA
Total Power Dissipation	Ptot Note 2	480	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Notes 1. Depend on the ESD protect device.

2. Mounted on 3.8 cm \times 9.0 cm \times 0.8 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

Document No. PU10768EJ02V0DS (2nd edition)
Date Published November 2009 NS

<R>

THERMAL RESISTANCE (TA = +25°C)

<R>

Parameter	Symbol	Ratings	Unit
Termal Resistance from Junction to Ambient Note	Rth _{j-a}	260	°C/W

Note Mounted on 3.8 cm \times 9.0 cm \times 0.8 mm (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE (TA = +25°C)

<R>

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Collector Current	lc	-	40	-	mA

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit		
DC Characteristics								
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	_	_	100	nA		
Emitter Cut-off Current	ІЕВО	V _{EB} = 0.4 V, I _C = 0 mA	_	_	100	nA		
DC Current Gain	hfe Note 1	VcE = 5 V, Ic = 15 mA	140	180	260	-		
RF Characteristics	RF Characteristics							
Gain Bandwidth Product	f⊤	VcE = 5 V, Ic = 40 mA, f = 1 GHz	_	10.5	_	GHz		
Insertion Power Gain	S _{21e} ²	VcE = 5 V, Ic = 40 mA, f = 1 GHz	9.5	11.5	_	dB		
Noise Figure (1)	NF1	$V_{\text{CE}} = 5 \text{ V, Ic} = 15 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt, }} Z_{\text{L}} = 50 \Omega$	-	0.75	1.15	dB		
Noise Figure (2)	NF2	$V_{\text{CE}} = 5 \text{ V, Ic} = 40 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, Z_{\text{L}} = Z_{\text{Lopt}}$	-	0.8	-	dB		
Associated Gain (1)	Ga1	$V_{\text{CE}} = 5 \text{ V, Ic} = 15 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = 50 \Omega$	9.0	11.0	-	dB		
Associated Gain (2)	Ga2	$V_{CE} = 5 \text{ V}, \text{ Ic} = 40 \text{ mA}, \text{ f} = 1 \text{ GHz}, $ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	-	12.0	-	dB		
Reverse Transfer Capacitance	Cre Note 2	VcB = 5 V, IE = 0 mA, f = 1 MHz	_	0.9	1.1	pF		
Maximum Stable Power Gain	MSG Note 3	VcE = 5 V, Ic = 40 mA, f = 1 GHz	11.0	13.0	_	dB		
Gain 1 dB Compression Output Power	Po (1 dB)	$\begin{aligned} &V_{\text{CE}} = 5 \text{ V, Ic }_{\text{(set)}} = 40 \text{ mA, f} = 1 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{aligned}$	-	23.5	-	dBm		
Output 3rd Order Intercept Point	OIP ₃	$V_{\text{CE}} = 5 \text{ V, Ic } (\text{set}) = 40 \text{ mA, f} = 1 \text{ GHz}, \\ \Delta f = 1 \text{ MHz, Zs} = Z_{\text{Sopt}}, Z_{\text{L}} = Z_{\text{Lopt}}$	-	35.5	-	dBm		

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded.

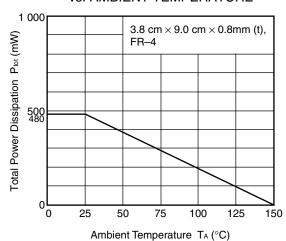
3. MSG =
$$\frac{S_{21}}{S_{12}}$$

hfe CLASSIFICATION

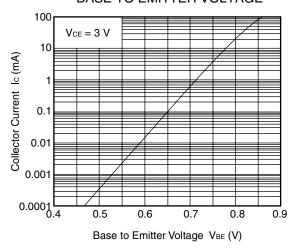
Rank	FB		
Marking	R7A		
h _{FE} Value	140 to 260		

<R> TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

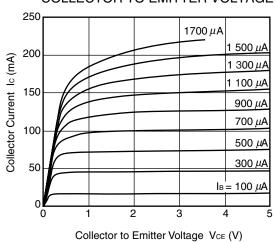
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

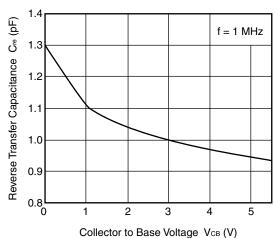


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

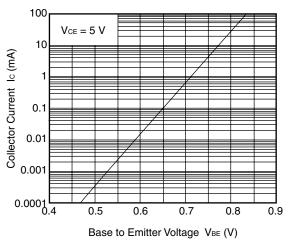


Remark The graphs indicate nominal characteristics.

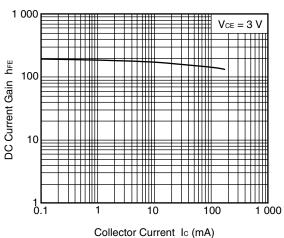
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



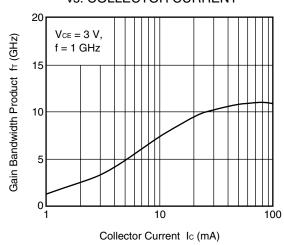
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE





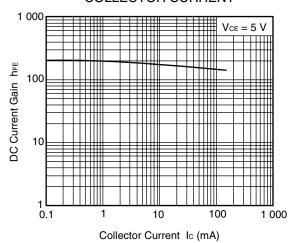


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

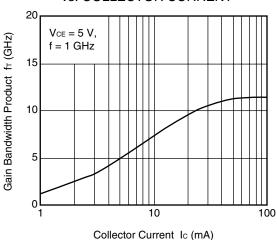


Remark The graphs indicate nominal characteristics.

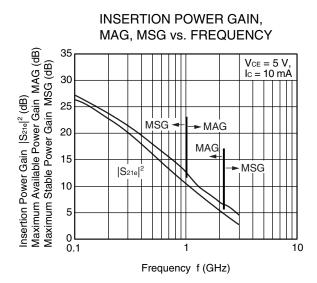
DC CURRENT GAIN vs. COLLECTOR CURRENT

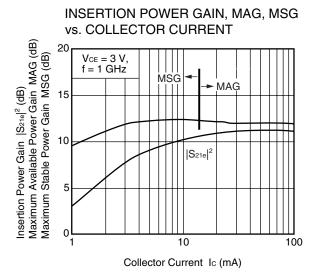


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

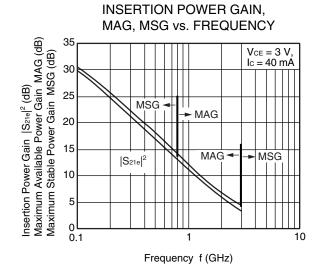


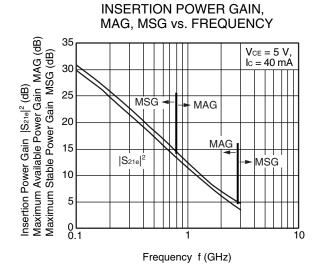
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY Maximum Available Power Gain MAG (dB) Maximum Stable Power Gain MSG (dB) 35 VcE = 3 V, lc = 10 mA 30 Insertion Power Gain |S21e|2 (dB) 25 MAG 20 MAG 15 |S_{21e} MSG 10 5 0.1 10 Frequency f (GHz)

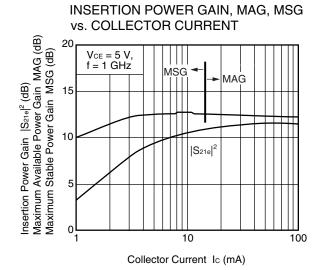




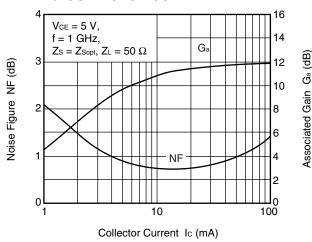
Remark The graphs indicate nominal characteristics.



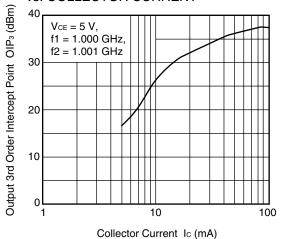




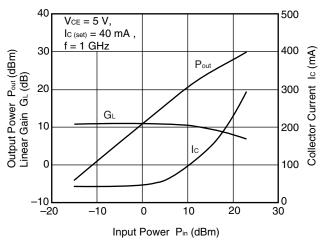
NOISE FIGURE, ASSOCIATED GAIN vs. COLLECTOR CURRENT



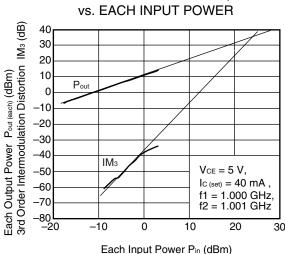
OUTPUT 3RD ORDER INTERCEPT POINT vs. COLLECTOR CURRENT



OUTPUT POWER, LINEAR GAIN, COLLECTOR CURRENT vs. INPUT POWER



EACH OUTPUT POWER, IM3



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

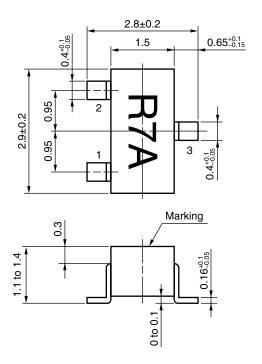
Click here to download S-parameters.

 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$

URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

3-PIN MINIMOLD (33 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Emitter
- 2. Base
- 3. Collector

7

- The information in this document is current as of November, 2009. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without the prior
 written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may
 appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of a customer's equipment shall be done under the full
 responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by
 customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. In addition, NEC Electronics products are not taken measures to prevent radioactive rays in the product design. When customers use NEC Electronics products with their products, customers shall, on their own responsibility, incorporate sufficient safety measures such as redundancy, fire-containment and anti-failure features to their products in order to avoid risks of the damages to property (including public or social property) or injury (including death) to persons, as the result of defects of NEC Electronics products.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and
 "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).